**Product data sheet** 

## 1. General description

Ultrafast power diode in a SMB package.

### 2. Features and benefits

- Fast switching
- SMB package
- High voltage capability
- Low forward voltage drop
- Low leakage current
- · Low thermal resistance
- · Soft recovery characteristic

## 3. Applications

- Discontinuous Current Mode (DCM) Power Factor Correction (PFC)
- use in switching power supplies, inverters and as free wheeling diodes
- · High frequency switched-mode power supplies

### 4. Quick reference data

#### Table 1. Quick reference data

Symbol	Parameter	Conditions	Values	Unit
Absolute	maximum rating			
$V_{RRM}$	repetitive peak reverse voltage		600	V
I <sub>F(AV)</sub>	average forward current	$\delta$ = 0.5; square-wave pulse; $T_{lead} \le$ 158 °C; Fig. 1; Fig. 2; Fig. 3	1	Α
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5 ; $t_p$ = 25 μs; $T_{lead} \le$ 158 °C; square-wave pulse	2	A
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	35	A
		$t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse	38	А

Ultrafast power diode

# 5. Pinning information

### **Table 2. Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K	cathode		× 14 .
2	A	anode	1 2	K — A 001aaa020

# 6. Ordering information

#### **Table 3. Ordering information**

Type number	Package Name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
MURS160B	SMB	MURS160BJ	Reel	3000	SMBS	25-May-2017

# 7. Marking

#### Table 4. Marking codes

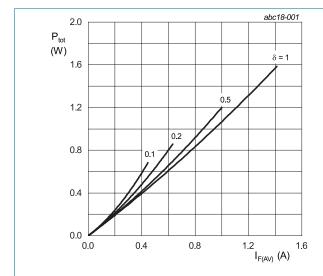
Type number	Marking codes
MURS160B	160B

# 8. Limiting values

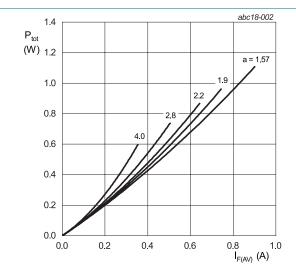
#### **Table 5. Limiting values**

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
$V_{RRM}$	repetitive peak reverse voltage		600	V
$V_{\text{RWM}}$	crest working reverse voltage		600	V
$V_R$	reverse voltage	DC	600	V
$I_{F(AV)}$	average forward current	$\delta$ = 0.5; square-wave pulse; $T_{lead} \le$ 158 °C; Fig. 1; Fig. 2; Fig. 3	1	Α
I <sub>FRM</sub>	repetitive peak forward current	$\delta$ = 0.5 ; $t_p$ = 25 $\mu$ s; $T_{lead} \le$ 158 °C; square-wave pulse	2	Α
I <sub>FSM</sub>	non-repetitive peak forward current	$t_p$ = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; Fig. 4	35	Α
		$t_p$ = 8.3 ms; $T_{J(init)}$ = 25 °C; sine-wave pulse	38	Α
T <sub>stg</sub>	storage temperature		-65 to 175	°C
T <sub>j</sub>	junction temperature		175	°C



$$\begin{split} & |_{\text{F(AV)}} = |_{\text{F(RMS)}} \times \sqrt{\delta} \\ & |_{\text{O}} = 0.934 \text{ V; R}_{\text{s}} = 0.1331 \text{ }\Omega \\ & \text{Fig. 1.} \quad \text{Forward power dissipation as a function of average forward current; square waveform; } \\ & \text{maximum values} \end{split}$$

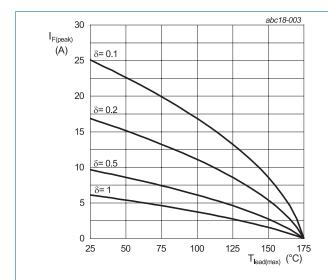


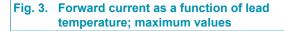
a = form factor =  $I_{F(RMS)}/I_{F(AV)}$  $V_o$  = 0.934 V;  $R_s$  = 0.1331  $\Omega$ 

Fig. 2. Forward power dissipation as a function of average forward current; sinusoidal waveform; maximum values

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**Ultrafast power diode** 





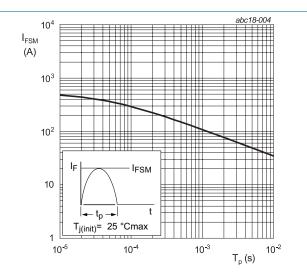


Fig. 4. Non-repetitive peak forward current as a function of pulse width; sinusoidal waveform; maximum values

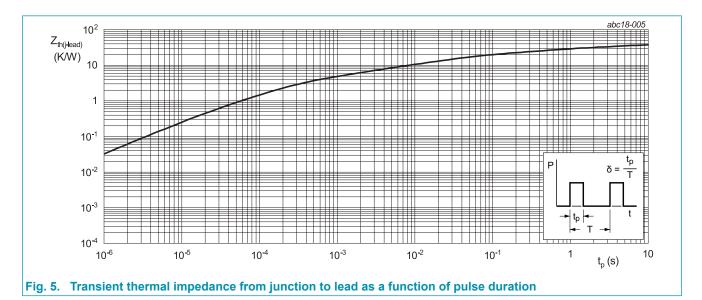
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### 9. Thermal characteristics

**Table 6. Thermal characteristics** 

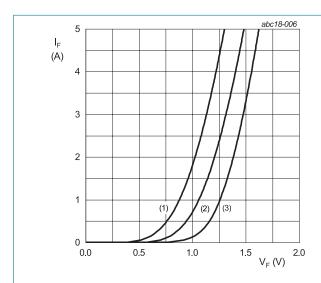
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{\text{th(j-lead)}}$	thermal resistance from junction to lead	<u>Fig. 5</u>	-	-	14	K/W
$R_{\text{th(j-a)}}$	thermal resistance from junction to ambient free air	in free air	-	115	-	K/W



## 10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static ch	aracteristics					
$V_{F}$	forward voltage	I <sub>F</sub> = 1 A; T <sub>j</sub> = 25 °C	-	-	1.25	V
		I <sub>F</sub> = 1 A; T <sub>j</sub> = 150 °C	-	-	1.05	V
I <sub>R</sub>	reverse current	V <sub>R</sub> = 600 V; T <sub>j</sub> = 25 °C	-	-	5	μA
		V <sub>R</sub> = 600 V; T <sub>j</sub> = 150 °C	-	-	150	μA
Dynamic	characteristics					
$Q_r$	reverse charge	$I_F = 1 \text{ A}$ ; $V_R = 400 \text{ V}$ ; $dI_F/dt = 200 \text{ A/us}$ ; $T_J = 25 \text{ °C}$ ; Fig. 7	-	45	-	nC
		I <sub>F</sub> = 1 A; V <sub>R</sub> = 400 V; dI <sub>F</sub> /dt = 200 A/us; T <sub>j</sub> = 125 °C; <u>Fig. 7</u>	-	81	-	nC
t <sub>rr</sub> ro	reverse recovery time	$I_F = 1 \text{ A}; V_R = 30 \text{ V}; dI_F/dt = 50 \text{ A/us};$ $T_j = 25 \text{ °C}; Fig. 7$	-	40	75	ns
		$I_F = 1 \text{ A}$ ; $V_R = 400 \text{ V}$ ; $dI_F/dt = 200 \text{ A/us}$ ; $T_j = 25 \text{ °C}$ ; Fig. 7	-	31	-	ns
		$I_F = 1 \text{ A}$ ; $V_R = 400 \text{ V}$ ; $dI_F/dt = 200 \text{ A/us}$ ; $T_j = 125 \text{ °C}$ ; Fig. 7	-	46	-	ns
		$I_F = 0.5 \text{ A}; I_R = 1 \text{ A}; I_{R(max)} = 0.25 \text{ A};$ $T_j = 25 ^{\circ}\text{C}; \text{ Step recovery}$	-	-	40	ns
I <sub>RM</sub>	peak reverse recovery current	$I_F = 1 \text{ A}$ ; $V_R = 400 \text{ V}$ ; $dI_F/dt = 200 \text{ A/us}$ ; $T_J = 25 \text{ °C}$ ; Fig. 7	-	2.9	-	А
		$I_F = 1 \text{ A}; V_R = 400 \text{ V}; dI_F/dt = 200 \text{ A/us};$ $T_i = 125 \text{ °C}; \frac{\text{Fig. 7}}{\text{C}}$	-	3.5	-	Α



 $\begin{array}{l} V_o=0.934~V;~R_s=0.1331~\Omega\\ (1)~T_j=150~^{\circ}C;~typical~values\\ (2)~T_j=150~^{\circ}C;~maximum~values\\ (3)~T_j=25~^{\circ}C;~maximum~values \end{array}$ 

Fig. 6. Forward current as a function of forward voltage

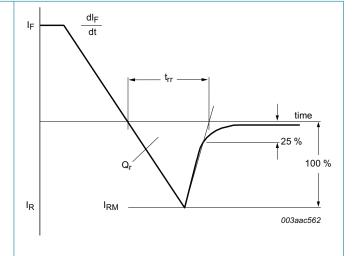
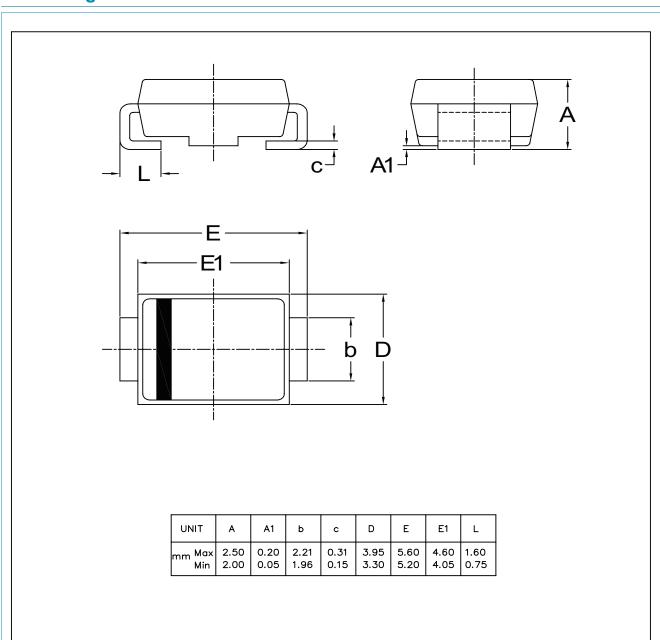


Fig. 7. Reverse recovery definitions; ramp recovery

# 11. Package outline



Remark: Dimensions D and E1 do not include mold flash.

#### Ultrafast power diode

## 12. Legal information

#### Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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# MURS160B

Ultrafast power diode

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